

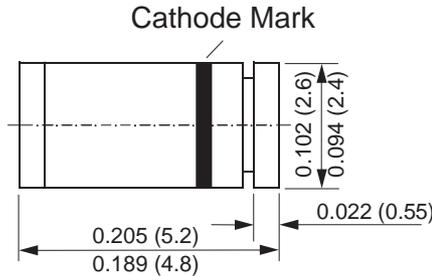


## Zener Diodes

**V<sub>Z</sub> Range** 100 to 180V  
**Power Dissipation** 1.0W

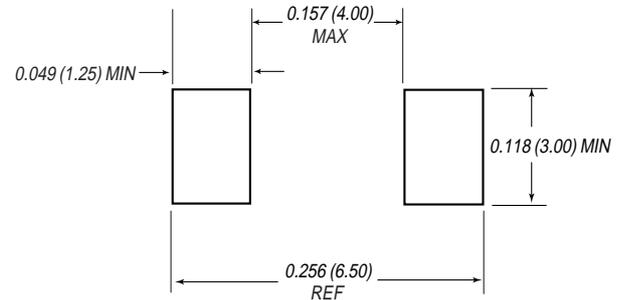


### Glass MELF



Dimensions in inches and (millimeters)

### Mounting Pad Layout



## Mechanical Data

**Case:** MELF Glass Case

**Weight:** approx. 0.25g

**Packaging Codes/Options:**

E4/5K per 13" reel (12mm tape), 10K/box  
25/1.5K per 7" reel (12mm tape), 12K/box

## Features

- Silicon Planar Power Zener Diodes
- For use in stabilizing and clipping circuits with higher power rating.
- The Zener voltages are graded according to the international E 12 standard. Smaller voltage tolerances are available upon request.
- These diodes are also available in the DO-41 case with the type designation ZPU100 ... ZPU180.

## Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

| Parameter                                    | Symbol            | Value              | Unit |
|--|-------------------|--------------------|------|
| Zener Current (see Table "Characteristics")  |                   |                    |      |
| Power Dissipation at T <sub>amb</sub> = 25°C | P <sub>tot</sub>  | 1.0 <sup>(1)</sup> | W    |
| Thermal Resistance Junction to Ambient Air   | R <sub>thJA</sub> | 170 <sup>(1)</sup> | °C/W |
| Junction Temperature                         | T <sub>j</sub>    | 150                | °C   |
| Storage Temperature Range                    | T <sub>s</sub>    | -55 to +150        | °C   |

**Notes:** (1) Valid provided that electrodes are kept at ambient temperature.

## Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

| Type   | Zener Voltage <sup>(1)</sup> at I <sub>ZT</sub> V <sub>Z</sub> (V) |     | Dynamic Resistance at I <sub>ZT</sub> f = 1 kHz r <sub>Zj</sub> (Ω) | Temp. Coeff. of Zener Voltage at I <sub>ZT</sub> α <sub>VZ</sub> (10 <sup>-4</sup> /°C) |     | Test current I <sub>ZT</sub> (mA) | Reverse Voltage at I <sub>R</sub> = 0.5 mA V <sub>R</sub> (V) | Admissible Zener current <sup>(2)</sup> at T <sub>amb</sub> = 25°C I <sub>Z</sub> (mA) |
|--------|--|-----|---|---|-----|-----------------------------------|---|--|
|        | Min  | Max |   | Min   | Max |                                   |   |  |
| ZMU100 | 88   | 110 | 140 (< 300)   | +9  | +13 | 5                                 | > 75  | 7  |
| ZMU120 | 107  | 134 | 170 (< 330)   | +9  | +13 | 5                                 | > 90  | 6  |
| ZMU150 | 130  | 165 | 200 (< 360)   | +9  | +13 | 5                                 | > 112   | 5  |
| ZMU180 | 160  | 200 | 220 (< 380)   | +9  | +13 | 5                                 | > 134   | 4  |

**Notes:** (1) Tested with pulses t<sub>p</sub> = 5 ms

(2) Valid provided that electrodes are kept at ambient temperature

# ZMU100 thru ZMU180

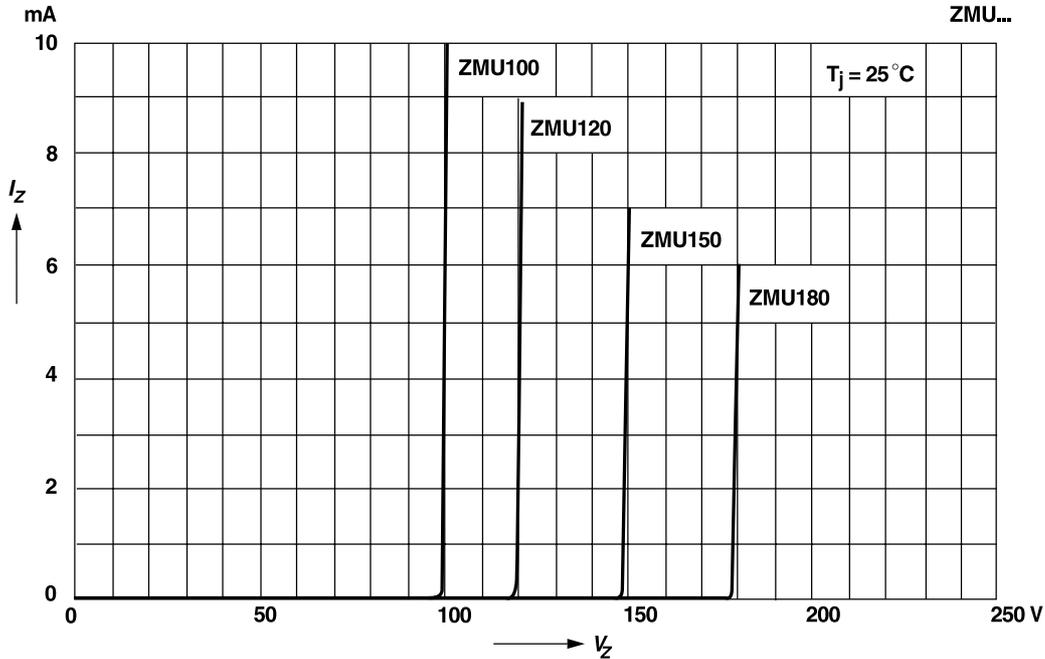
Vishay Semiconductors  
formerly General Semiconductor



## Ratings and Characteristic Curves ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

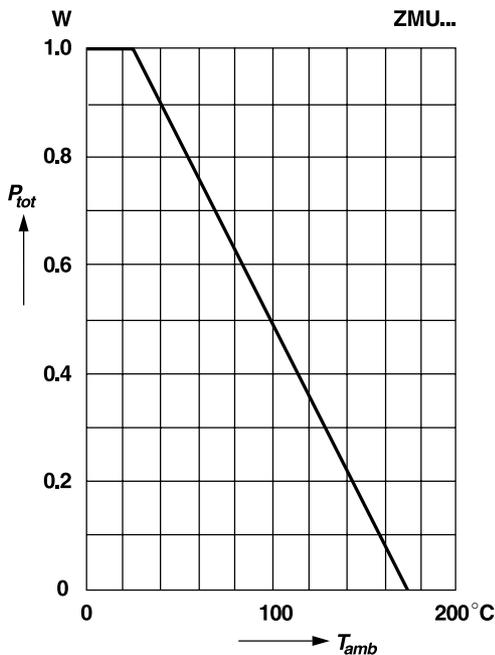
### Breakdown characteristics

$T_j = \text{constant (pulsed)}$



### Admissible power dissipation versus ambient temperature

Valid provided that electrodes are kept at ambient temperature



### Pulse thermal resistance versus pulse duration

Valid provided that electrodes are kept at ambient temperature

